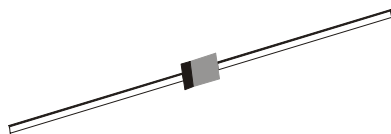


SILIICON PLANAR ZENER DIODES

BZX83C
2V7 to 56V
500mW

DO- 35
Glass Axial Package



Best suited for Industrial, Military and Space Applications. The glass passivated diode chip in the hermetically sealed glass package with double studs provides excellent stability and reliability.

ABSOLUTE MAXIMUM RATINGS (T_a=25°C)

DESCRIPTION	SYMBOL	VALUE	UNIT
Power Dissipation	P _{TA}	500	mW
Junction Temperature	T _j	175	°C
Storage Temperature	T _{stg}	- 55 to +175	°C
Thermal Resistance - Junction to Ambient in free air	R _{th(j-a)}	300	°C/W

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

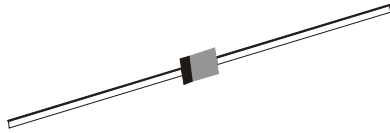
Forward Voltage @ I_F=200mA V_F < 1.2 V

Device	V _{ZT} @ I _{ZT} *		r _{ZT} @ I _{ZT} *	I _{ZT}	r _{ZK} @ I _{ZK}	I _{ZK}	Temp. Coeff of Zener Voltage typ (%/°C)	I _R @ T _a 25°C max	V _R	I _{ZM} max
	min (V)	max (V)	max (W)	(mA)	max (W)	(mA)		(mA)	(V)	(mA)
BZX83C 2V7	2.50	2.90	90	5.0	600	1.0	-0.07	100	1.0	135
BZX83C 3V0	2.80	3.20	90	5.0	600	1.0	-0.07	60	1.0	125
BZX83C 3V3	3.10	3.50	90	5.0	600	1.0	-0.06	30	1.0	115
BZX83C 3V6	3.40	3.80	90	5.0	600	1.0	-0.06	20	1.0	105
BZX83C 3V9	3.70	4.10	90	5.0	600	1.0	-0.05	10	1.0	95
BZX83C 4V3	4.00	4.60	80	5.0	600	1.0	-0.03	5	1.0	90
BZX83C 4V7	4.40	5.00	80	5.0	600	1.0	-0.01	2	1.0	85
BZX83C 5V1	4.80	5.40	60	5.0	550	1.0	+0.01	1	1.0	75
BZX83C 5V6	5.20	6.00	40	5.0	450	1.0	+0.03	1	1.0	70
BZX83C 6V2	5.80	6.60	10	5.0	200	1.0	+0.04	1	2.0	64
BZX83C 6V8	6.40	7.20	8	5.0	150	1.0	+0.05	1	3.0	58
BZX83C 7V5	7.00	7.90	7	5.0	50	1.0	+0.05	1	3.5	53
BZX83C 8V2	7.70	8.70	7	5.0	50	1.0	+0.06	1	4.0	47
BZX83C 9V1	8.50	9.60	10	5.0	50	1.0	+0.06	1	5.0	43
BZX83C 10	9.40	10.60	15	5.0	70	1.0	+0.07	1	6.0	40
BZX83C 11	10.40	11.60	20	5.0	70	1.0	+0.07	1	8.2	36
BZX83C 12	11.40	12.70	20	5.0	90	1.0	+0.07	1	9.1	32
BZX83C 13	12.40	14.10	25	5.0	110	1.0	+0.07	1	10	29
BZX83C 15	13.80	15.60	30	5.0	110	1.0	+0.08	1	11	27
BZX83C 16	15.30	17.10	40	5.0	170	1.0	+0.08	1	12	24
BZX83C 18	16.80	19.10	55	5.0	170	1.0	+0.08	1	13	21
BZX83C 20	18.80	21.20	55	5.0	220	1.0	+0.08	1	15	20
BZX83C 22	20.80	23.30	58	5.0	220	1.0	+0.08	1	16	18
BZX83C 24	22.80	25.60	80	5.0	220	1.0	+0.08	1	18	16
BZX83C 27	25.10	28.90	80	5.0	250	1.0	+0.09	1	20	14

*Pulse Condition : 20ms ≤ tp ≤ 50ms . Duty Cycle ≤ 2%

SILICON PLANAR ZENER DIODES

BZX83C
2V7 to 56V
500mW



DO- 35
Glass Axial Package

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

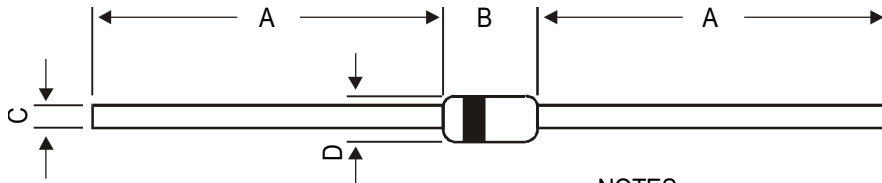
Device	V _{ZT} @ I _{ZT} *		r _{ZT} @ I _{ZT} *	I _{ZT}	r _{ZK} @ I _{ZK}	I _{ZK}	Temp. Coeff of Zener Voltage typ (%/°C)	I _R @ T _a 25°C max (mA)	V _R	I _{ZM}
	min (V)	max (V)	max (W)	(mA)	max (W)	(mA)			(V)	max (mA)
BZX83C 30	28.00	32.00	90	5.0	250	1.0	+0.09	1	22	13
BZX83C 33	31.00	35.00	90	5.0	250	1.0	+0.09	1	24	12
BZX83C 36	34.00	38.00	90	5.0	250	1.0	+0.09	1	27	11
BZX83C 39	37.00	41.00	100	2.5	600	0.5	+0.09	1	30	10
BZX83C 43	40.00	46.00	100	2.5	700	0.5	+0.09	1	33	9.2
BZX83C 47	44.00	50.00	120	2.5	1000	0.5	+0.09	1	36	8.5
BZX83C 51	48.00	54.00	135	2.5	1000	0.5	+0.09	1	39	7.8
BZX83C 56	52.00	60.00	145	2.5	1000	0.5	+0.09	1	43	7.0

***Pulse Condition : 20ms ≤ tp ≤50ms . Duty Cycle ≤2%**

BZX83C
2V7 to 56V
500mW

DO- 35
Glass Axial Package

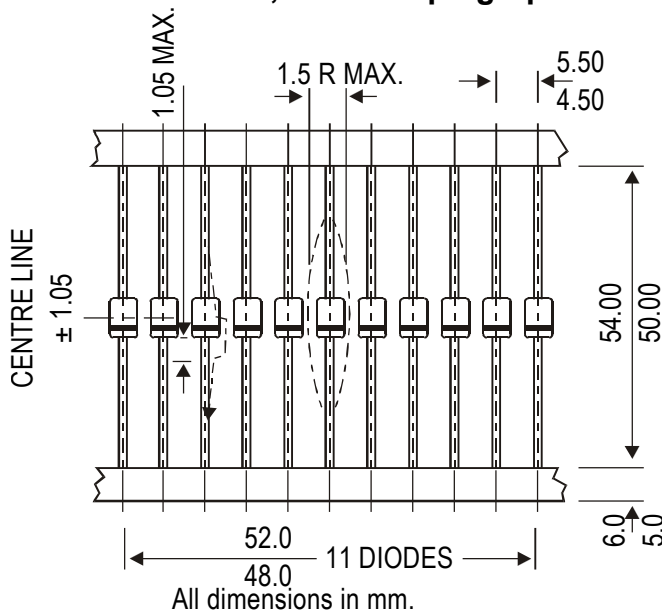
DO-35 Glass Axial Package



- NOTES**
1. Cathode is marked by Band.
 2. All dimensions are in mm.

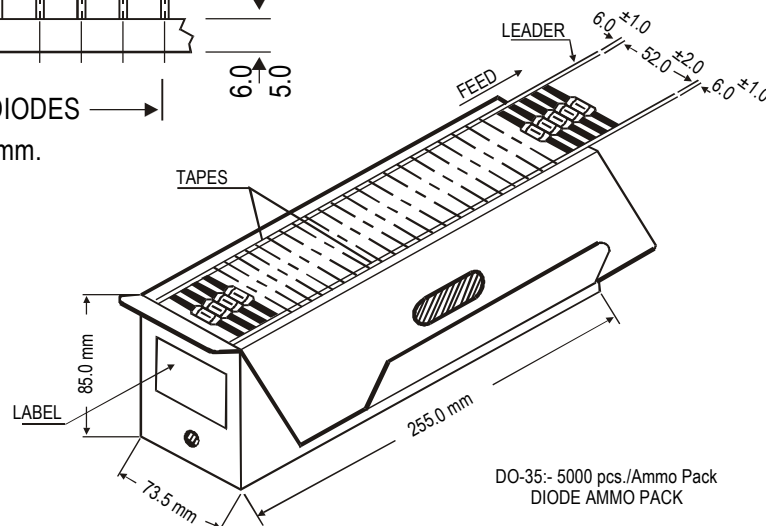
DIM	MIN	MAX
A	25.40	—
B	3.03	4.44
C	0.46	0.56
D	1.52	2.29

DO-35, 52mm Taping Specification



52 mm Taping Specification

1. T & A indicates Axial Tape & Ammo packing (52 mm Tape Spacing).
2. 300 mm (min) leader tape on every spool.
3. No. of empty places allowed 0.25% without consecutive empty places.
4. Ends of leads shall preferably not protrude beyond the tapes.
5. Components shall be held sufficiently in the tape or tapes so that they can not come free in normal handling.



DO-35:- 5000 pcs./Ammo Pack
 DIODE AMMO PACK

On request also available in 26 mm Tape and Ammo Pack

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
DO-35 T&A	5K/ammo box	0.88 kg/5K pcs	10" x 3.5" x 3.5"	5.0K	12.7" x 12.7" x 20"	125.0K	25 kgs

Disclaimer

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